THERMAL DATA

R _{thj-case} Thermal Resistance Junction-case	Max	1.76	°C/W
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ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

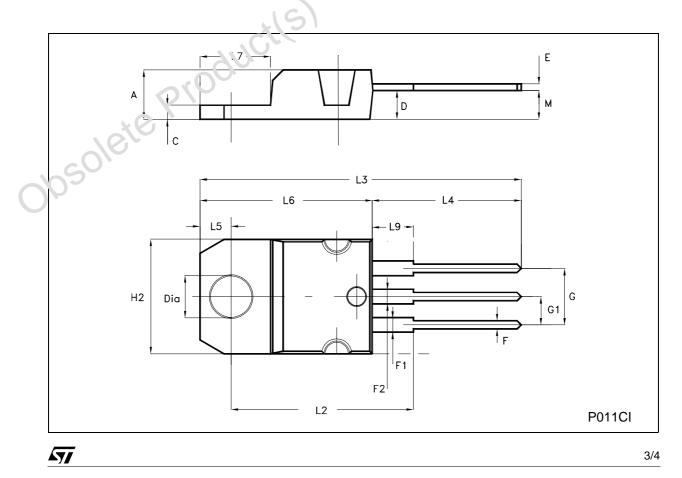
Symbol	Parameter	Test	t Conditions	Min.	Тур.	Max.	Unit
I _{CER}	Collector Cut-off Current ($R_{BE} = 50\Omega$)	V _{CE} = 240V	$T_c = 125^{\circ}C$			3	mA
I _{CEX}	Collector Cut-off Current (V _{BE} = -1.5V)	V _{CE} = 240V	$T_{c} = 125^{\circ}C$			1	mA
I _{EBO}	Emitter Cut-off Current $(I_C = 0)$	V _{EB} = 5 V				1	mA
V _{CEO(sus)} *	Collector-Emitter Sustaining Voltage (I _B = 0)	I _C = 0.2 A	L = 25mH	120	21	ctl	Þv
V_{EBO}	Emitter-Base Voltage (I _C = 0)	I _E = 50mA		7	00.	30	V
V _{CE(sat)} *	Collector-Emitter Saturation Voltage	I _C = 4A I _C = 8A	$I_{\rm B} = 0.4 \text{A}$ $I_{\rm B} = 0.8 \text{A}$			0.7 1.5	V V
$V_{BE(sat)^*}$	Base-Emitter Saturation Voltage	I _C = 8A	I _B = 0.8A			2	V
t _{on} t _s t _f	RESISTIVE LOAD Turn-on Time Storage Time Fall Time	V _{CC} = 90V V _{BE} = - 6V R _{BB} = 3.75Ω	$i_{1,2} = 8A$ $i_{2,1} = 0.8A$		0.4 0.5 0.12	0.8 1.2 0.25	ms μs μs
t _s t _f	INDUCTIVE LOAD Storage time Fall Time	$V_{C} = 9JV$ $ I_{P1} = 0.8A$	I _C = 8A V _{BE} = - 5V		0.6 0.04		μs μs
t _s t _f	Storage Time Fall Time	$L_B = 1 \mu H$ $V_{CC} = 90V$ $I_{B1} = 0.8A$ $L_B = 1 \mu H$	$I_{C} = 8 A$ $V_{BE} = -5V$ $T_{c} = 125^{\circ}C$			2 0.15	μs μs

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DIM.		mm			inch		
DIIVI.	MIN.	TYP.	MAX.	MIN.	N. TYP.		
А	4.40		4.60	0.173		0.181	
С	1.23		1.32	0.048		0.052	
D	2.40		2.72	0.094		0.107	
Е	0.49		0.70	0.019		0.027	
F	0.61		0.88	0.024		0.034	
F1	1.14		1.70	0.044		0.067	
F2	1.14		1.70	0.044		0.007	
G	4.95		5.15	0.194		<u> </u>	
G1	2.40		2.70	0.094	11	0.106	
H2	10.00		10.40	0.394	~0,~	0.409	
L2		16.40			0.645		
L4	13.00		14.00	0.511		0.551	
L5	2.65		2.95	0.104	·	0.116	
L6	15.25		15.75	(1500		0.620	
L7	6.20		6.60	0.244		0.260	
L9	3.50		3.93	0.137		0.154	
М		2.60			0.102		
DIA.	3.75		3.00	0.147		0.151	





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